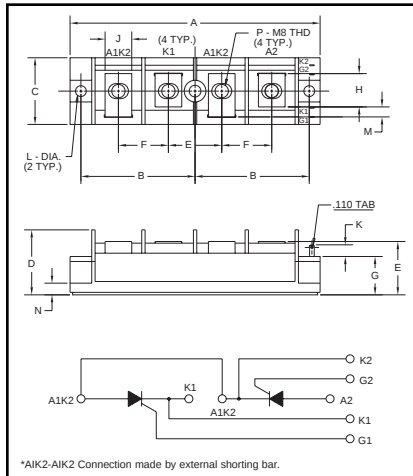


Dual SCR POW-R-BLOK™ Modules 130 Amperes/1200-1600 Volts



Outline Drawing

Dimension	Inches	Millimeters
A	5.906	150
B	2.697±0.02	68.5±0.2
C	1.575	40
D	1.535	39
E	1.260	32
F	1.181	30
G	0.906	23
H	0.787	20
J	0.630	16
K	0.276	7
L	0.256±0.008 Dia.	Dia. 6.5±0.2
M	0.236	6
N	0.197	5
P	M8 Metric	M8



CM531213, CM531613
Dual SCR POW-R-BLOK™ Modules
130 Amperes/1200-1600 Volts

Description:

Powerex Dual SCR POW-R-BLOK™ Modules are designed for use in applications requiring phase control and isolated packaging. The modules are isolated for easy mounting with other components on common heatsinks.

Features:

- ☐ Isolated Mounting
- ☐ Glass Passivated Chips
- ☐ Metal Baseplate
- ☐ Low Thermal Impedance

Applications:

- ☐ Battery Supplies
- ☐ Bridge Circuits
- ☐ AC and DC Motor Control
- ☐ Tap Changers
- ☐ Lighting Control

Ordering Information:

Select the complete eight digit module part number you desire from the table below.
Example: CM531613 is a 1600 Volt, 130 Ampere Dual SCR POW-R-BLOK™ Module.

Type	Voltage Volts (x100)	Current Rating Amperes (x10)
CM53	12 16	13

CM531213, CM531613
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Absolute Maximum Ratings

Characteristics	Symbol	CM531213	CM531613	Units
Peak Forward Blocking Voltage	V_{DRM}	1200	1600	Volts
Transient Peak Forward Blocking Voltage (Non-Repetitive), $t < 5ms$	V_{DSM}	1350	1700	Volts
DC Forward Blocking Voltage	$V_{D(DC)}$	960	1280	Volts
Peak Reverse Blocking Voltage	V_{RRM}	1200	1600	Volts
Transient Peak Reverse Blocking Voltage (Non-Repetitive), $t < 5ms$	V_{RSM}	1350	1700	Volts
DC Reverse Blocking Voltage	$V_{R(DC)}$	960	1280	Volts
RMS On-State Current	$I_T(RMS)$	205	205	Amperes
Average On-State Current, $T_C = 78^\circ C$	$I_T(AV)$	130	130	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (60Hz)	I_{TSM}	2600	2600	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	I_{TSM}	2365	2365	Amperes
I^2t (for Fusing), 8.3 milliseconds	I^2t	28000	28000	A^2sec
Critical Rate-of-Rise of On-State Current*	di/dt	100	100	Amperes/ μs
Peak Gate Power Dissipation	P_{GM}	10	10	Watts
Average Gate Power Dissipation	$P_{G(AV)}$	3.0	3.0	Watts
Peak Forward Gate Voltage	V_{GFM}	10	10	Volts
Peak Reverse Gate Voltage	V_{GRM}	5.0	5.0	Volts
Peak Forward Gate Current	I_{GFM}	4.0	4.0	Amperes
Storage Temperature	T_{STG}	-40 to 125	-40 to 125	$^\circ C$
Operating Temperature	T_J	-40 to 125	-40 to 125	$^\circ C$
Maximum Mounting Torque M6 Mounting Screw	—	26	26	in.-lb.
Maximum Mounting Torque M8 Terminal Screw	—	72	72	in.-lb.
Module Weight (Typical)	—	300	300	Grams
V Isolation	V_{RMS}	2500	25000	Volts

* $T_J = 125^\circ C$, $I_G = 1.0A$, $V_D = 1/2 V_{DRM}$

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Electrical and Thermal Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	CM531213/CM531613	Units
Blocking State Maximums				
Forward Leakage Current, Peak	I_{DRM}	$T_j = 125^\circ\text{C}$, $V_{\text{DRM}} = \text{Rated}$	30	mA
Reverse Leakage Current, Peak	I_{RRM}	$T_j = 125^\circ\text{C}$, $V_{\text{RRM}} = \text{Rated}$	30	mA
Conducting State Maximums				
Peak On-State Voltage	V_{TM}	$I_{\text{TM}} = 390\text{A}$	1.5	Volts
Switching Minimums				
Critical Rate-of-Rise of Off-State Voltage	dv/dt	$T_j = 125^\circ\text{C}$, $V_D = 2/3 V_{\text{DRM}}$	500	Volts/ μs
Thermal Maximums				
Thermal Resistance, Junction-to-Case	$R_{\theta(\text{J-C})}$	Per Module	0.22	$^\circ\text{C/Watt}$
Thermal Resistance, Case-to-Sink (Lubricated)	$R_{\theta(\text{C-S})}$	Per Module	0.05	$^\circ\text{C/Watt}$
Gate Parameters Maximums				
Gate Current-to-Trigger	I_{GT}	$V_D = 6\text{V}$, $R_L = 2\Omega$	100	mA
Gate Voltage-to-Trigger	V_{GT}	$V_D = 6\text{V}$, $R_L = 2\Omega$	3.0	Volts
Non-Triggering Gate Voltage	V_{GDM}	$T_j = 125^\circ\text{C}$, $V_D = 1/2 V_{\text{DRM}}$	0.25	Volts

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